Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application.

Listing of Claims:

- 1. Cancelled
- 2. Cancelled
- Cancelled
- 4. (Previously Presented) The method according to claim 13 wherein steps a)- b) are performed at pressures of 0.1 Bar or higher.
 - 5. Cancelled
 - 6. Cancelled
 - 7. Cancelled
 - 8. Cancelled
 - 9. Cancelled
 - 10. Cancelled
- 11. (Previously Presented) The method according to claim 13 further including the step of performing a post-deposition etch to remove fluorocarbon residue from areas where its presence is undesirable.
 - 12. Cancelled
- 13. (Previously Presented) In a method of making an electronic device in which a conductive electrode has been formed over a substrate, comprising:
- a) providing an oxidizing plasma in a processing station to modify the properties of the conductive electrode by using shaped and appropriately positioned plasma producing electrodes to produce the oxygencontaining plasma in the processing station; and
- b) producing a fluorocarbon plasma in the processing station to form a fluorocarbon layer over the modified conductive electrode and using the shaped electrodes to produce a spatially modulated fluorocarbon plasma in the chamber, which forms a fluorocarbon layer in selected areas of the substrate electrode structure including over the substrate electrode structure.
- 14. (Previously Presented) The method of claim 13 wherein the conductive electrode is ITO.

- 15. (Currently Amended) In a method of making an electronic device in which a conductive electrode has been formed over a substrate, comprising:
- a) providing an oxidizing plasma in a processing station at a pressure greater than 0.1 Bar to modify the properties of the conductive electrode by using appropriately positioned plasma producing electrodes to produce the oxygen-containing plasma in the processing station; and
- b) producing a fluorocarbon plasma in the processing station at a pressure greater than 0.1 Bar to form a fluorocarbon layer over the modified conductive electrode by selecting a mixture of gases including a fluorine fluorocarbon-bearing gas and hydrogen containing gas which will cause a thicker deposition of the fluorocarbon layer over the electrode than regions adjacent to the electrodes.
- 16. (Currently Amended) The method according to claim 15 wherein the mixture of gases contains hydrogen, a noble gas and is at least one fluorocarbon gas which does not contain hydrogen., a noble gas, and a hydrogen containing gas.
- 17. (Currently Amended) The method of claim 16-15 wherein the gas wherein the fluorocarbon-bearing gas mixtures contains CF₄, helium and CHF₃.
- 18. (Previously Presented) The method of claim 15 wherein the electrode is ITO.